

1. An electron moves in a 1D crystal with lattice constant $a = 5 \text{ \AA}$.
 - i. Find the wavevector k at the Brillouin zone boundary where Bragg reflection occurs.
 - ii. If the electron behaves like a free particle, calculate its energy at this k . (Use free electron mass).
1. Given the energy dispersion relation for a 1D crystal as $E(k) = E_0 - 2t \times \cos(ka)$, where $t = 1 \text{ eV}$ and $a = 0.3 \text{ nm}$, calculate the effective mass of an electron near $k = 0$. Plot the velocity of an electron as a function of wavevector within the first Brillouin zone.
2. For a free electron, $E(k) = \hbar^2 k^2 / 2m_0$. If a periodic potential modifies this to $E(k) = \hbar^2 k^2 / 2m^*$, where $m^* = 0.1 \times m_0$, what does this imply about electron's motion in the crystal?
3. A semiconductor has a bandgap of 2.26 eV .
 - i. If you shine photons of wavelength 900 nm , will it excite an electron from the valence band to the conduction band?
 - ii. What are the wavelengths that can be transmitted (or reflected) through this semiconductor?
 - iii. Comment on the colour of this semiconductor.
4. Compare direct and indirect bandgap semiconductors and give examples of each. Why are direct bandgap materials preferred for optoelectronic devices?